8S2TH02I thru 8S2TH06I

8S2TH02I/8S2TH04I/8S2TH06I

16.0 Ampere Ceramic Insulated Dual Series Connection Ultra Fast Recovery Rectifiers



- * Latest FRED technology with super fast recovery time
- ★ Low forward voltage drop

Pb Free Plating Product

- High current capability
- * Low reverse leakage current
- ★ High surge current capability

Application

- ★ Automotive Inverters and Solar Inverters
- ★ Plating Power Supply, SMPS, Motor Control and UPS
- * Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- * Case: TO-220AC heatsink with inner ceramic insulated
- ★ Epoxy: UL 94V-0 rate flame retardant
- Terminals: Solderable per MIL-STD-202 method 208
- ★ Polarity: As marked on diode body
- ★ Mounting position: Any
- ★ Weight: 2.0 gram approximately

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

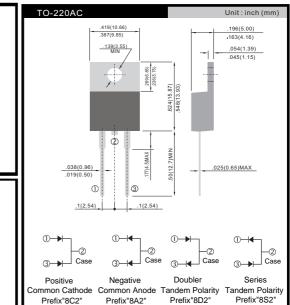
For capacitive load, derate current by 20%.

	SYMBOL	8S2TH02I	8S2TH04I	8S2TH06I	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=100°C(Total Device)	IF(AV)	16.0		A	
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	175	150		A
Maximum Instantaneous Forward Voltage @ 8.0 A (Per Diode)	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	lr	5.0 100			uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	25-35			nS
Typical junction Capacitance (Note 2)	CJ	90			pF
Typical Thermal Resistance (Note 3)	Rejc	1.5			°C/W
Operating Junction and Storage Temperature Range	Тј, Tstg	-55 to + 150			°C

NOTES : (1) Reverse recovery test conditions IF = 0.5A, R= 1.0A, Irr = 0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

(3) Thermal Resistance junction to case.





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BoHS



